



BSS84

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	I _D T _A = +25°C
-50V	10Ω @ V _{GS} = -5V	-130mA

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (BSS84Q)

Description and Applications

This MOSFET has been designed to minimize on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- General-purpose interfacing switches
- Power-management functions
- Analog switches

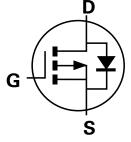
Mechanical Data

- Package: SOT23
- Package Material: UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)

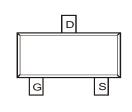
SOT23 (Standard)



Top View



Equivalent Circuit



Top View

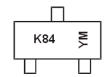
Ordering Information (Note 4)

Part Number	Backago	Packing		
Fait Number	Package	Qty.	Carrier	
BSS84-7-F	SOT23 (Standard)	3000	Tape & Reel	
BSS84-13-F	SOT23 (Standard)	10000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



K84 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} or \underline{Y} = Year (ex: L = 2024) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2003	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	Р	-	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	-50	V
Drain-Gate Voltage R _{GS} ≤ 20kΩ		VDGR	-50	V
Gate-Source Voltage	Continuous	Vgss	±20	V
Drain Current (Note 5)	Continuous	ID	-130	mA
Pulsed Drain Current		IDM	-1.2	Α

Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)			1 -71	1		
Drain-Source Breakdown Voltage	BV _{DSS}	-50	_		V	$V_{GS} = 0V, I_{D} = -250\mu A$
		_	_	-1	μA	V _{DS} = -50V, V _{GS} = 0V, T _J = +25°C
Zero Gate Voltage Drain Current	IDSS	_	_	-2	μA	$V_{DS} = -50V$, $V_{GS} = 0V$, $T_{J} = +125$ °C
		_	_	-100	nA	$V_{DS} = -25V$, $V_{GS} = 0V$, $T_{J} = +25$ °C
Gate-Body Leakage	Igss	_	_	±10	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	Vgs(th)	-0.8	_	-2.0	V	V _{DS} = V _{GS} , I _D = -1mA
Static Drain-Source On-Resistance	RDS(ON)	_	3.2	10	Ω	Vgs = -5V, ID = -0.100A
Forward Transconductance	grs	0.05	_	_	S	V _{DS} = -25V, I _D = -0.1A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss	_	24.6	45	pF	
Output Capacitance	Coss	_	4.7	25	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	2.8	12	pF	
Gate Resistance	Rg	_	916	_	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	0.28		nC	
Total Gate Charge (V _{GS} = -10V)	Qg	_	0.59	_	nC	101/ 1 0 1 1
Gate-Source Charge	Q _{gs}	—	0.09	_	nC	$V_{DS} = -10V, I_{D} = -0.1A$
Gate-Drain Charge	Qgd	_	0.08	_	nC	
Turn-On Delay Time	t _{D(ON)}	_	10	_	ns	$V_{DD} = -30V, I_D = -0.27A,$
Turn-Off Delay Time	t _{D(OFF)}	_	18		ns	Rgen = 50Ω , Vgs = -10V

Notes:

^{5.} Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html. 6. Short duration pulse test used to minimize self-heating effect.

^{7.} Guaranteed by design. Not subject to production testing.



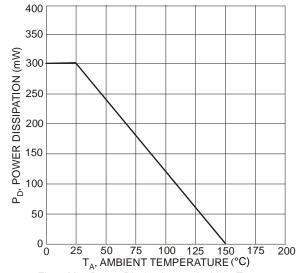
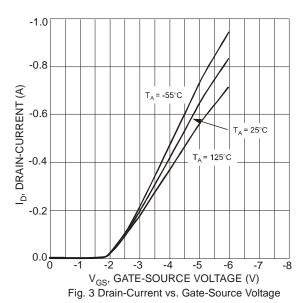
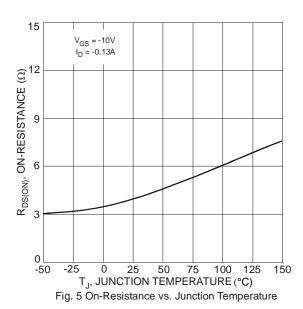


Fig. 1 Max Power Dissipation vs. Ambient Temperature





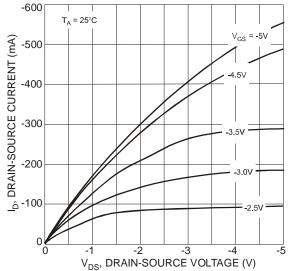


Fig. 2 Drain-Source Current vs. Drain-Source Voltage

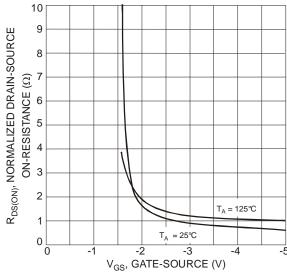


Fig. 4 On-Resistance vs. Gate-Source Voltage

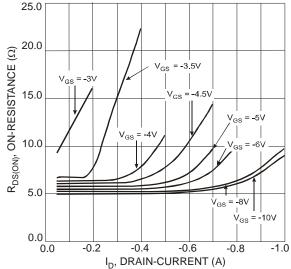
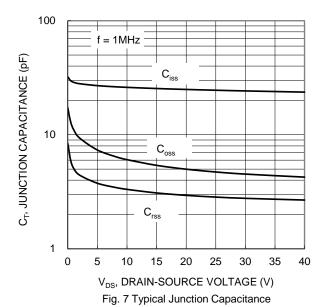
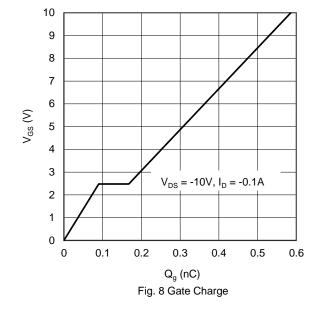
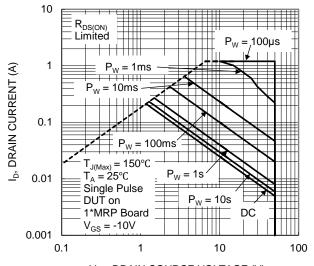


Fig. 6 On-Resistance vs. Drain-Current









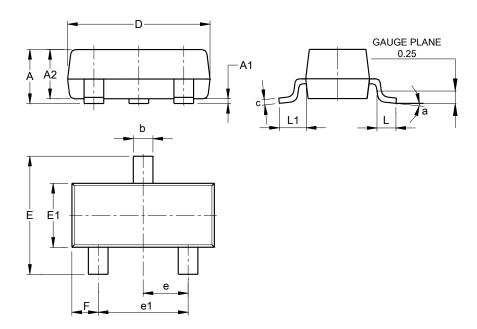
V_{DS}, DRAIN-SOURCE VOLTAGE (V) Fig. 9 SOA, Safe Operation Area



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

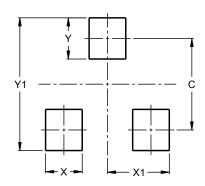
SOT23 (Standard)



S	SOT23 (Standard)							
Dim	Min	Max	Тур					
Α	0.90	1.15	1.025					
A1	0.00	0.10	0.05					
A2	0.85	1.10	0.975					
b	0.30	0.51	0.40					
С	0.080	0.202	0.11					
D	2.80	3.00	2.90					
Е	2.25	2.55	2.40					
E1	1.20	1.40	1.30					
е	0.89	1.03	0.915					
e1	1.78	2.05	1.83					
F	0.40	0.60	0.535					
L1	0.45	0.61	0.55					
L	0.25	0.55	0.40					
а	0°	8°						
All Dimensions in mm								

Suggested Pad Layout

SOT23 (Standard)



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Y	0.9
Y1	29



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